NSN 5961-01-184-2829

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-184-2829 **Inclosure Material:** Glass **Overall Length:** Between 0.135 inches and 0.165 inches **Terminal Length:** 1.250 inches **Overall Diameter:** Between 0.050 inches and 0.070 inches **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.017 inches and 0.023 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, dc **Power Rating Per Characteristic:** 400.0 milliwatts any acceptable absolute **Capacitance Rating In Picofarads:** 0.5 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig:

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